

Photocathode Endeavors at SLAC National Accelerator Laboratory

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Photocathode Physics for Photoinjectors

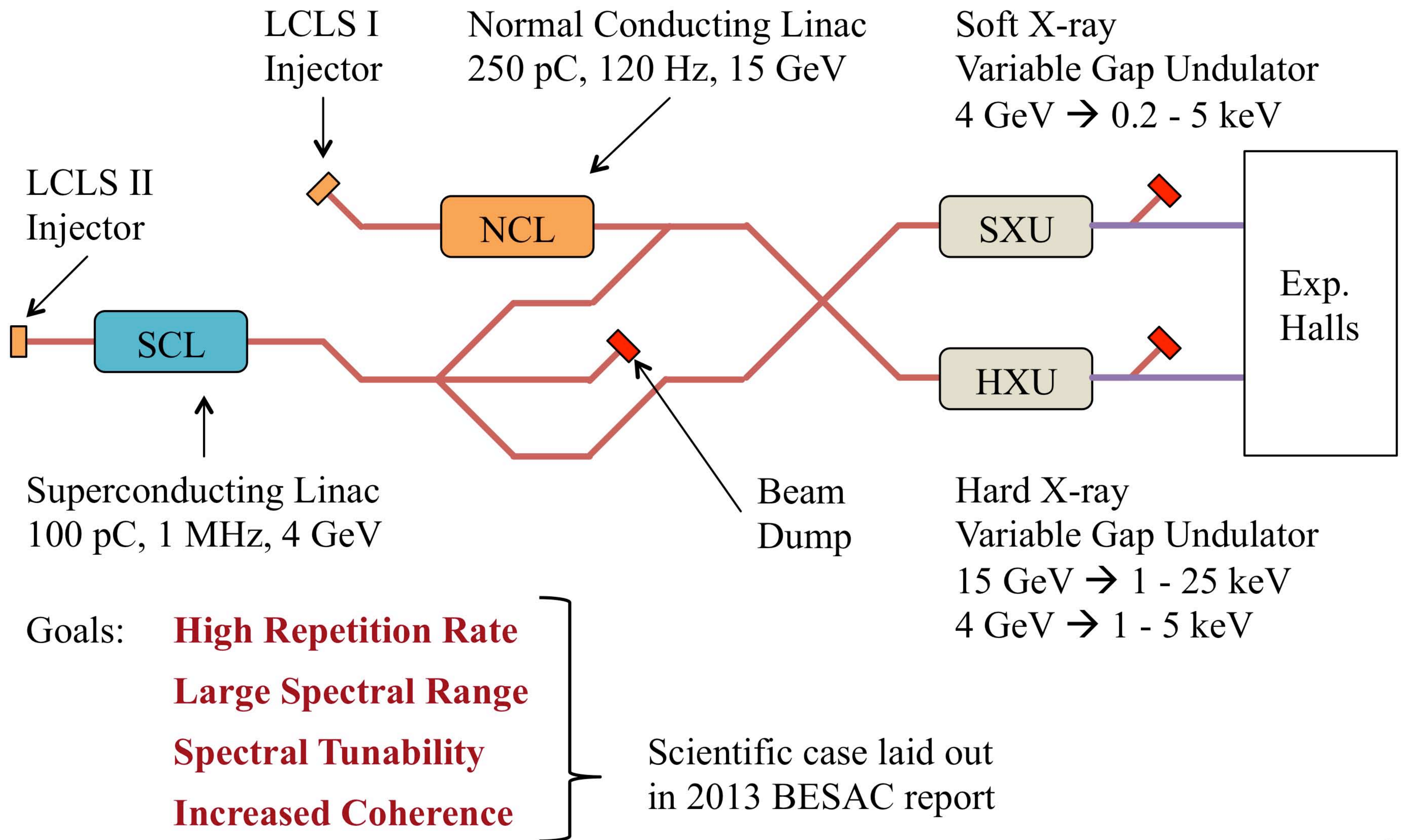
October 17-19, 2016

Thomas Jefferson National Accelerator Facility

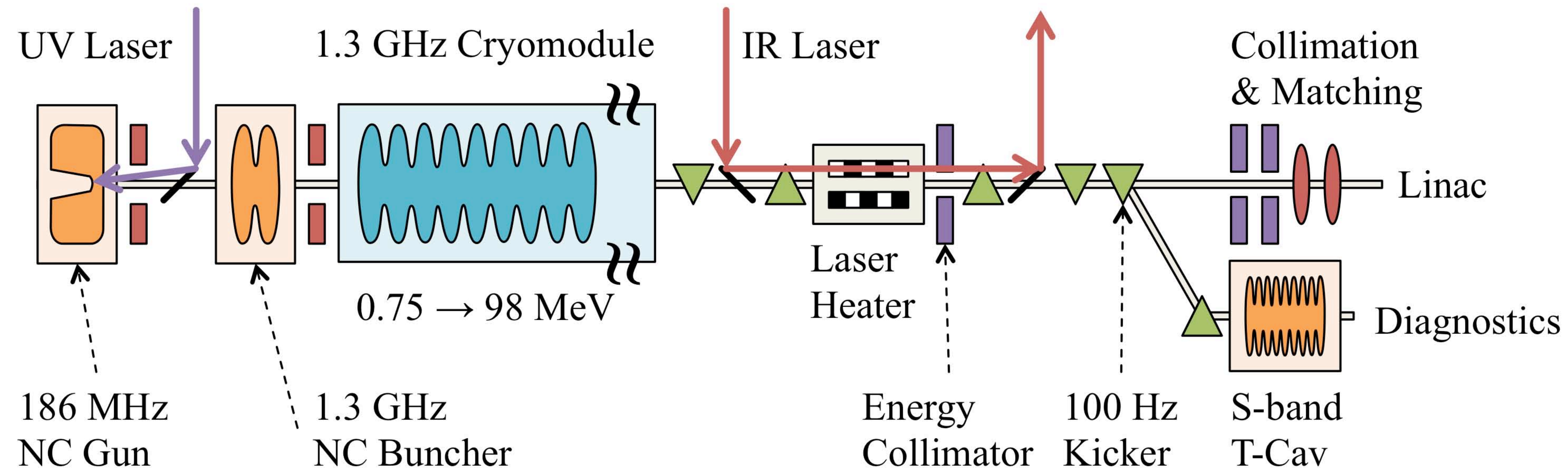
Outline

- **Supplying Photocathodes for the LCLS II**
- Modest Photocathode Optimization for Future FELs
- Simulations for Predicting Significant Photocathode Improvements

LCLS II



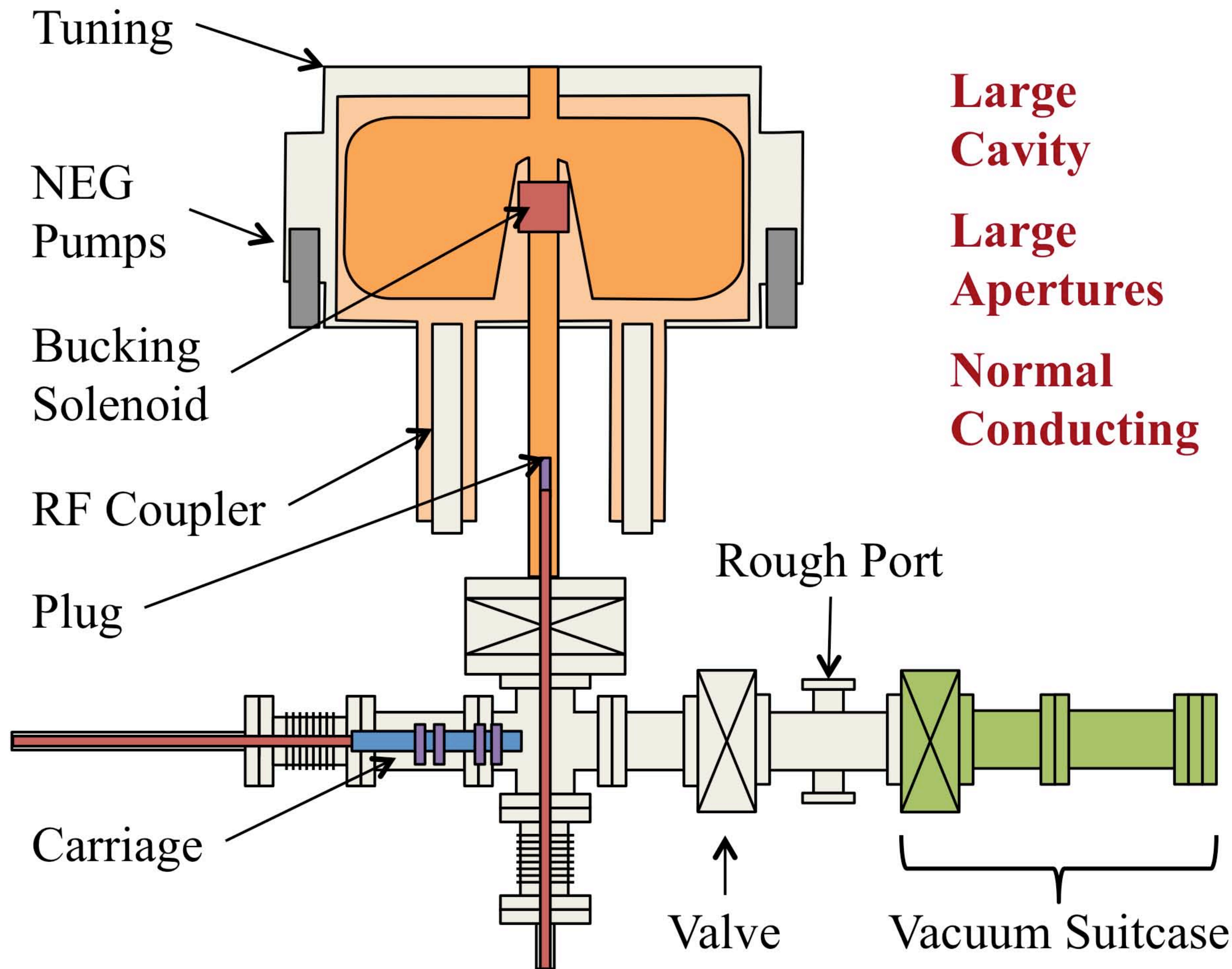
LCLS II Injector



Repetition Rate	0.929 MHz
Bunch Charge	100, 10 - 300 pC
Peak Current	12, 4 - 50 A
95% Slice Emittance	0.4, 0.2 - 0.6 μm
Bunch Length	0.3 - 10 mm
Slice Energy Spread	1 - 5 keV

Photocathode QE	> 0.5 %
Intrinsic Emittance	< 1 $\mu\text{m}/\text{mm}$
1/e Lifetime	> 10 days
UV @ Photocathode	300 nJ
1 nJ \rightarrow 1 pC @ 0.5% QE	
IR @ Laser Heater	15 μJ
15 μJ , 30 ps \rightarrow 20 keV	

LCLS II VHF Normal Conducting RF Gun



**Large
Cavity**

**Large
Apertures**

**Normal
Conducting**

- Dissipate CW heat load
- High vacuum conductivity
High QE photocathodes
- Reliability

Frequency	186 MHz
Gradient	20 MV/m
Energy	750 keV
Vacuum	$< 5 \times 10^{-10}$ torr

K. Baptiste et al., NIMA 599, 9 (2009)

F. Sannibale et al., PRST-AB 15, 103501 (2012)

Photocathodes for the LCLS II

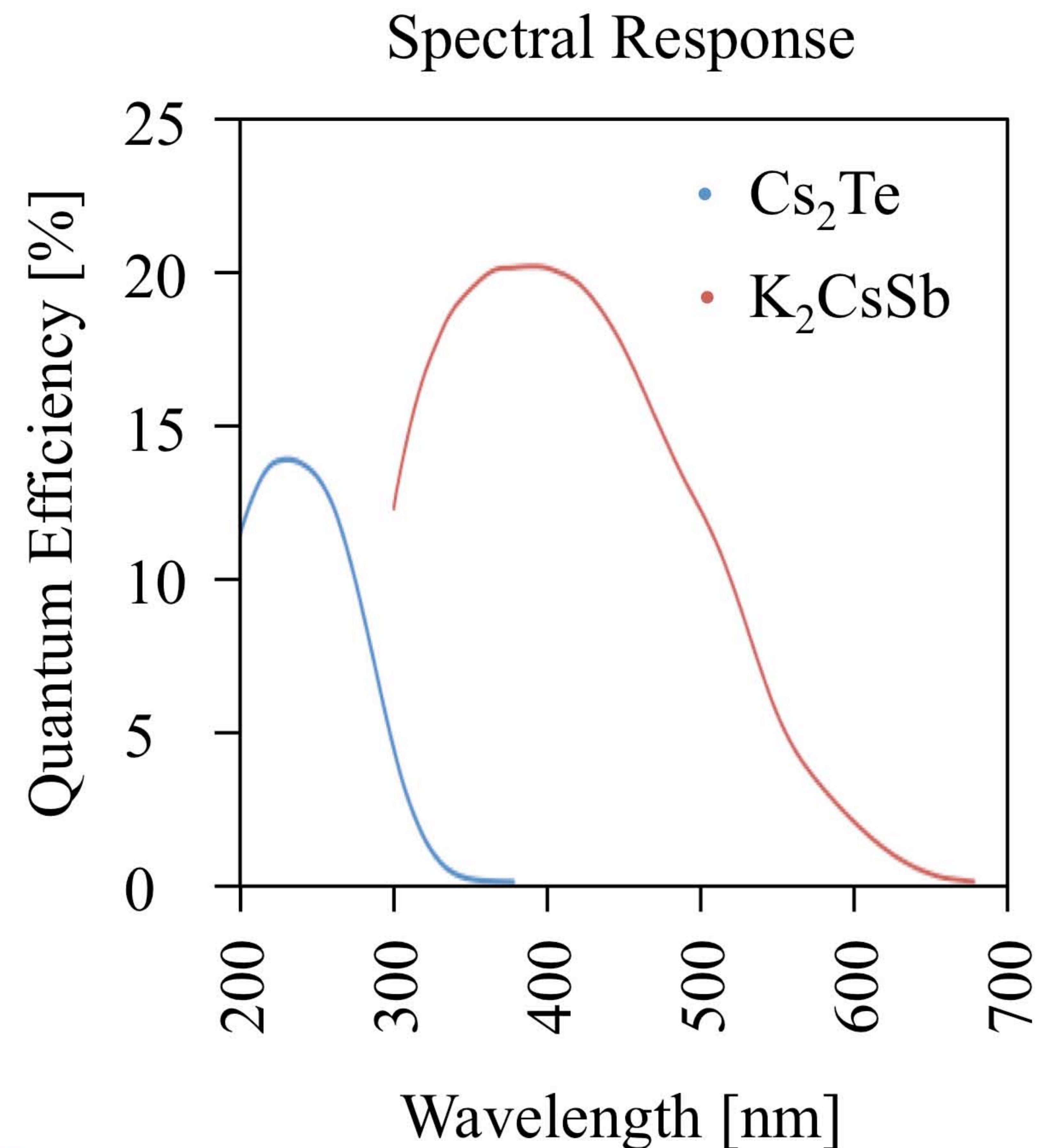
Performance summary of photocathodes at APEX

		Cs ₂ Te*	K ₂ CsSb
		INFN	LBNL
Vacuum Requirement	[torr]	< 10 ⁻⁹	< 10 ⁻¹⁰
Laser Wavelength	[nm]	263	526
Initial QE	[%]	> 10	≤ 8
Intrinsic Emittance	[μm/mm]	0.7-0.8	< 0.60
Service Life	[days]	50	
Storage Life	[days]	∞	> 30

*D. Filippetto et al., APL 107, 042104 (2015)

Conservative approach →

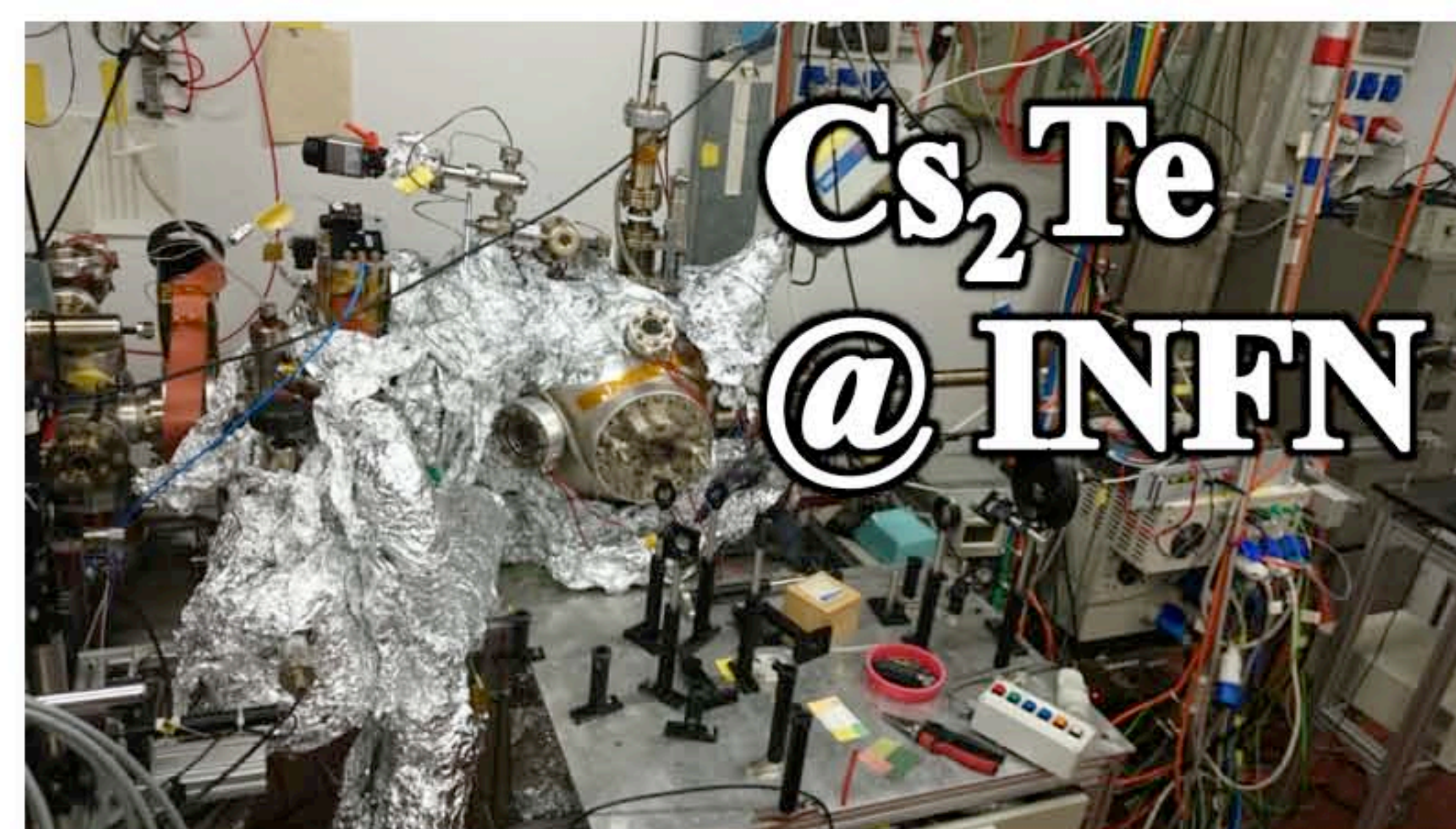
Cs₂Te was chosen as the LCLS II baseline



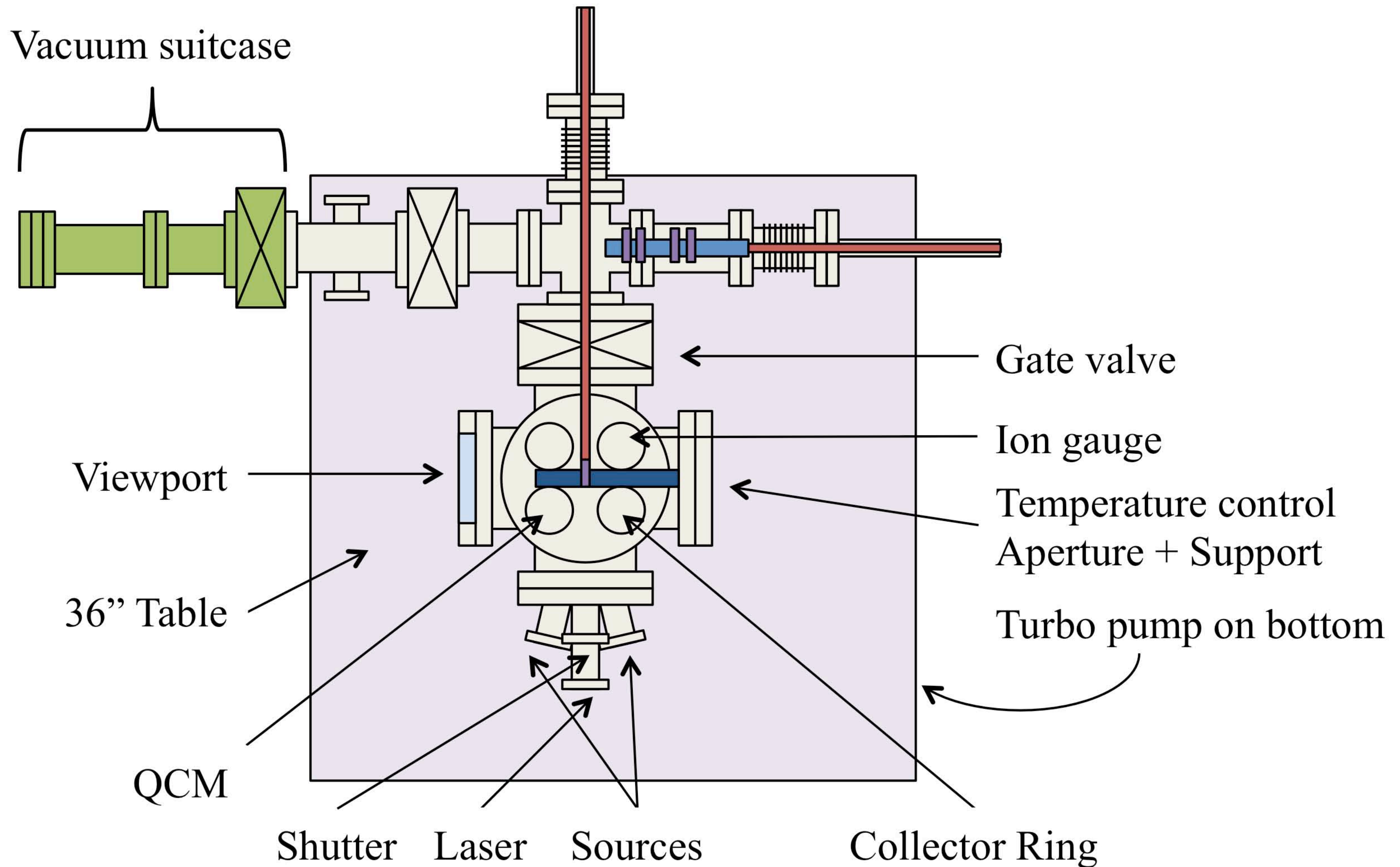
Providing Photocathodes for the LCLS II

	Calendar Year				1 7				1 8				1 9			
	Quarter				1	2	3	4	1	2	3	4	1	2	3	4
LCLS Shutdown																
Injector Installation																
Injector Commissioning																
Purchase Photocathodes																
Appropriate Lab Space																
Diagnostic System Commissioning																
Deposition System Commissioning																
Photocathodes Produced at SLAC																

Suppliers



Initial Conceptual Design of a Deposition System for LCLS II Photocathodes

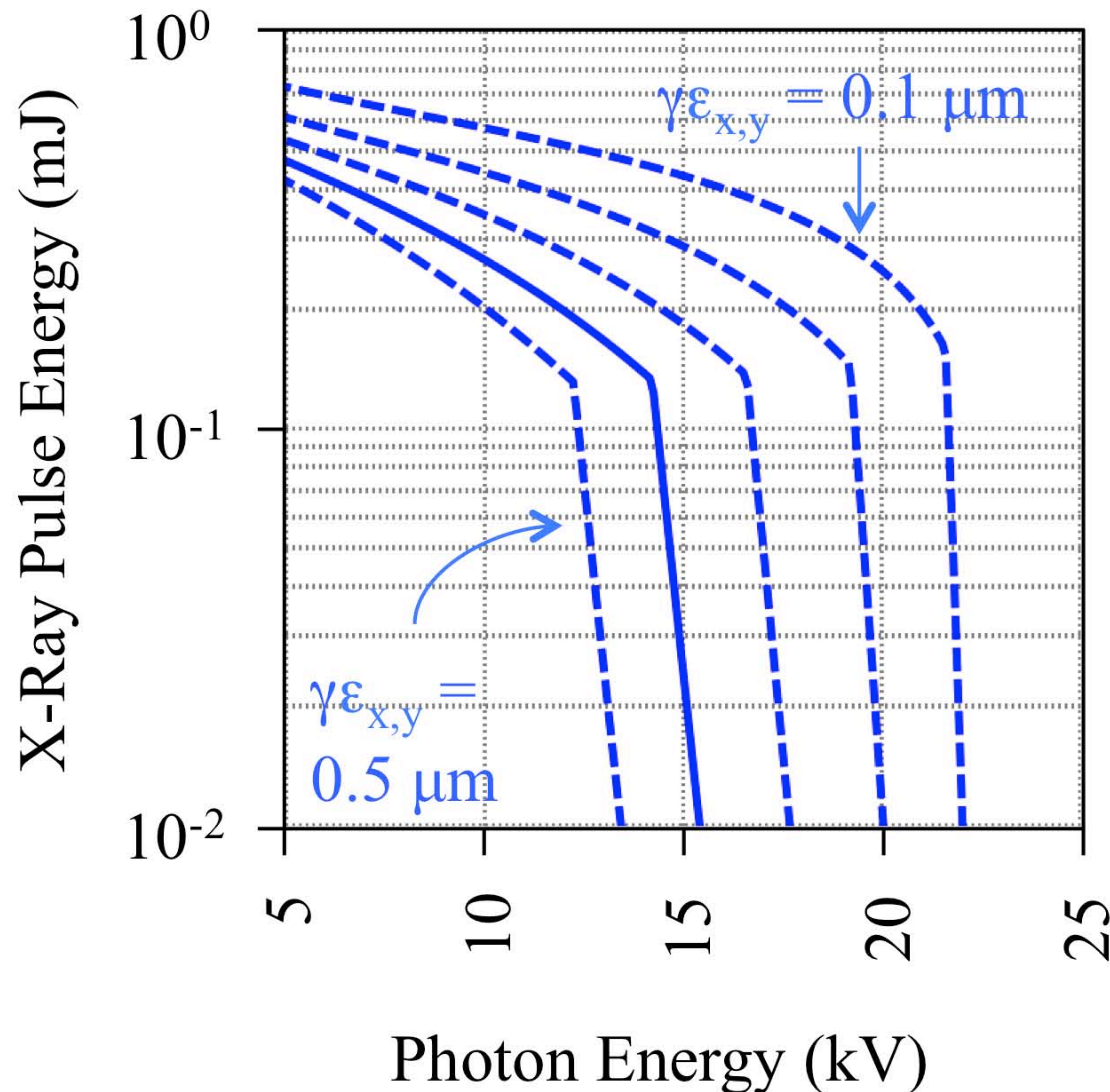


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Future FELs Need Lower Emittance

LCLS II HXU



I_{pk}	= 1 kA	E	= 8 GeV
Q	= 100 pC	σ_E	= 0.5 MeV
L_u	= 140 m	$\langle\beta_{x,y}\rangle$	= 20 m
λ_u	= 26 mm	p_f	= 0.8

FEL radiated power is a function of the FEL parameter, ρ , which in turn depends implicitly on emittance, ϵ_x , through σ_x .

$$\rho[\epsilon_x] = \left(\left(\frac{I}{I_A} \right) \left(\frac{\lambda_u}{2\pi\sigma_x[\epsilon_x]} \right)^2 \left(\frac{K}{\sqrt{2}} \left(J_0 \left[\frac{K^2}{4+2K^2} \right] - J_1 \left[\frac{K^2}{4+2K^2} \right] \right) \right)^2 \left(\frac{1}{2\gamma} \right)^3 \right)^{1/3}$$

M. Xie, PAC'95, Dallas, USA, 183-185.

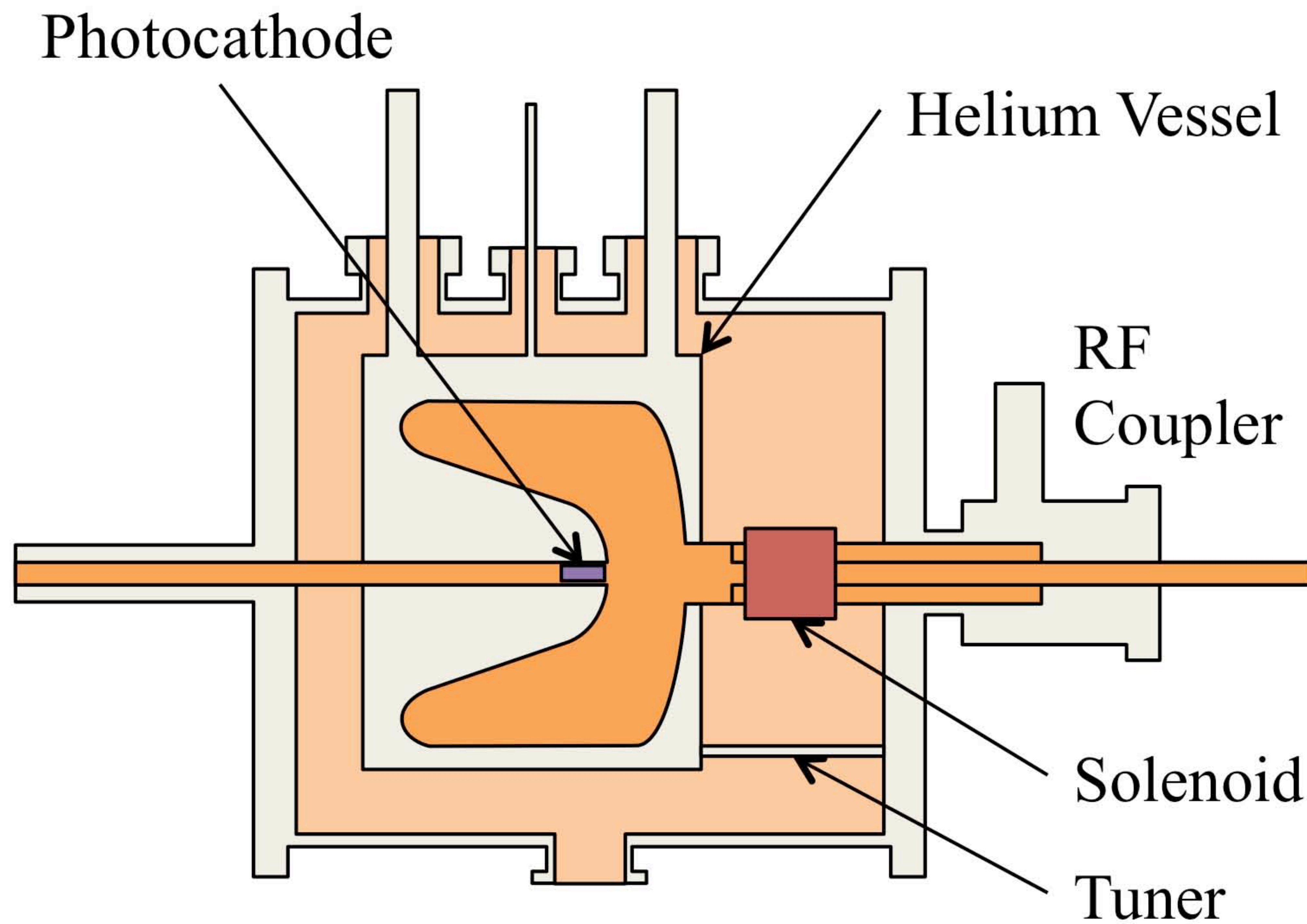
Reducing emittance:

- Increases photon pulse energy
- Extends accessible spectral range
- Increases transverse coherence

LCLS II: 0.4 μm @ 100-pC

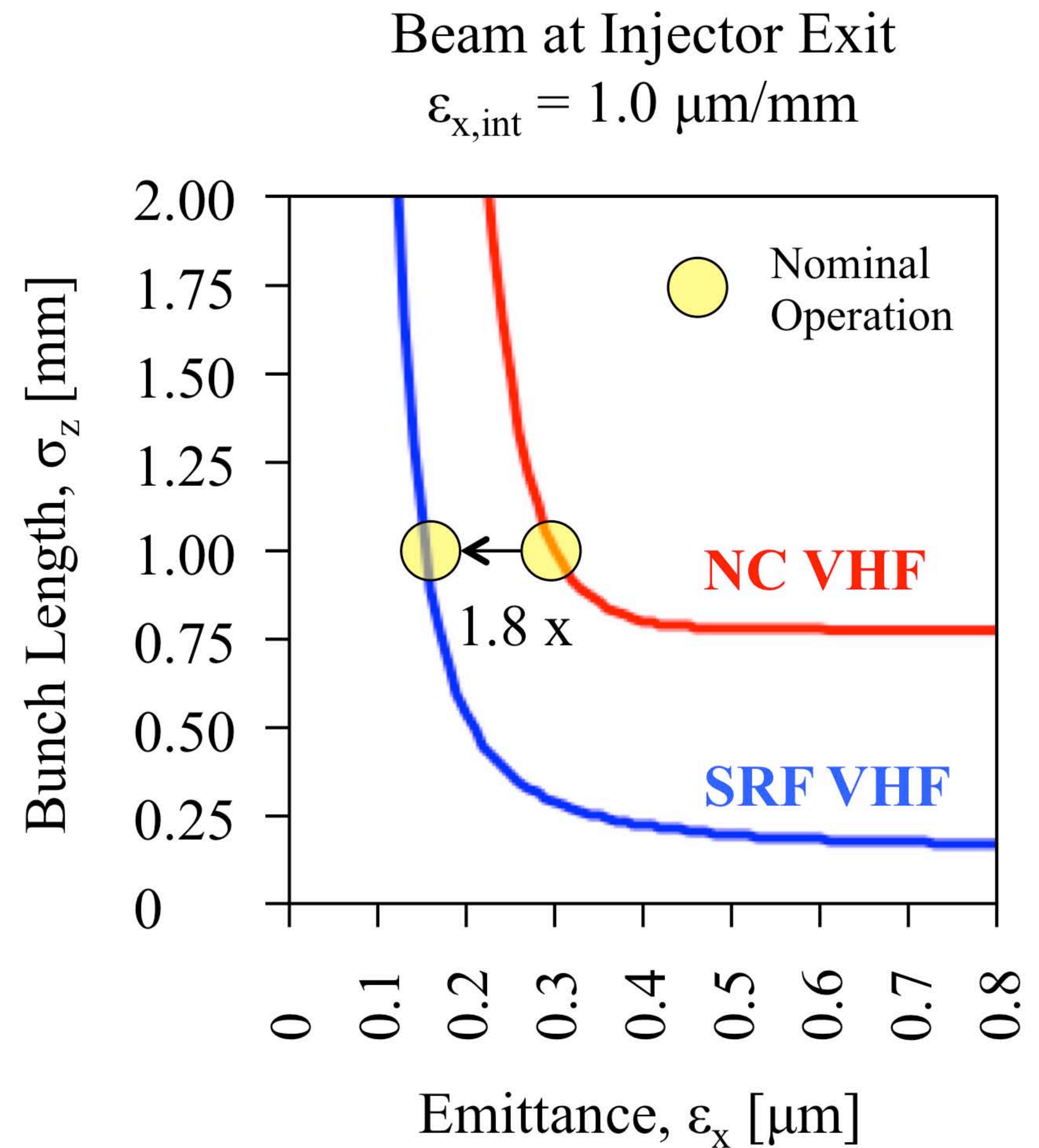
**Factor of 4 reduction needed for
> 20-keV radiation from 8 GeV linac**

WiFEL VHF SRF Gun



J. Bisognano et al., PAC'13, TUPMA19

Frequency	200 MHz
Gradient	45 MV/m
Energy	4.0 MeV



R. Li, DOE Injector Workshop

Photoemission from Free Electron Like Metals

Sommerfeld Free Electron Model

Electronic states and occupational probabilities

- 1.) Electrons bound by uniform potential
- 2.) Constant density of states
- 3.) Occupation from Fermi-Dirac statistics

Spicer 3-Step Photoemission Model

Identifies a sequence of steps in photoemission

- 1.) Absorb photons, ΔE normal to surface
- 2.) Diffuse to surface
- 3.) Escape, $\Delta E = \mu + \phi - \hbar\omega$ normal to surface

Intrinsic Emittance

$$\frac{\varepsilon_n}{\sigma_{x,y}} = \sqrt{\frac{m^*}{m} \frac{kT}{mc^2}} \sqrt{\frac{Li_3 \left[-\text{Exp} \left[\frac{\hbar\omega - \phi + \Delta\phi}{kT} \right] \right]}{Li_2 \left[-\text{Exp} \left[\frac{\hbar\omega - \phi + \Delta\phi}{kT} \right] \right]}}$$

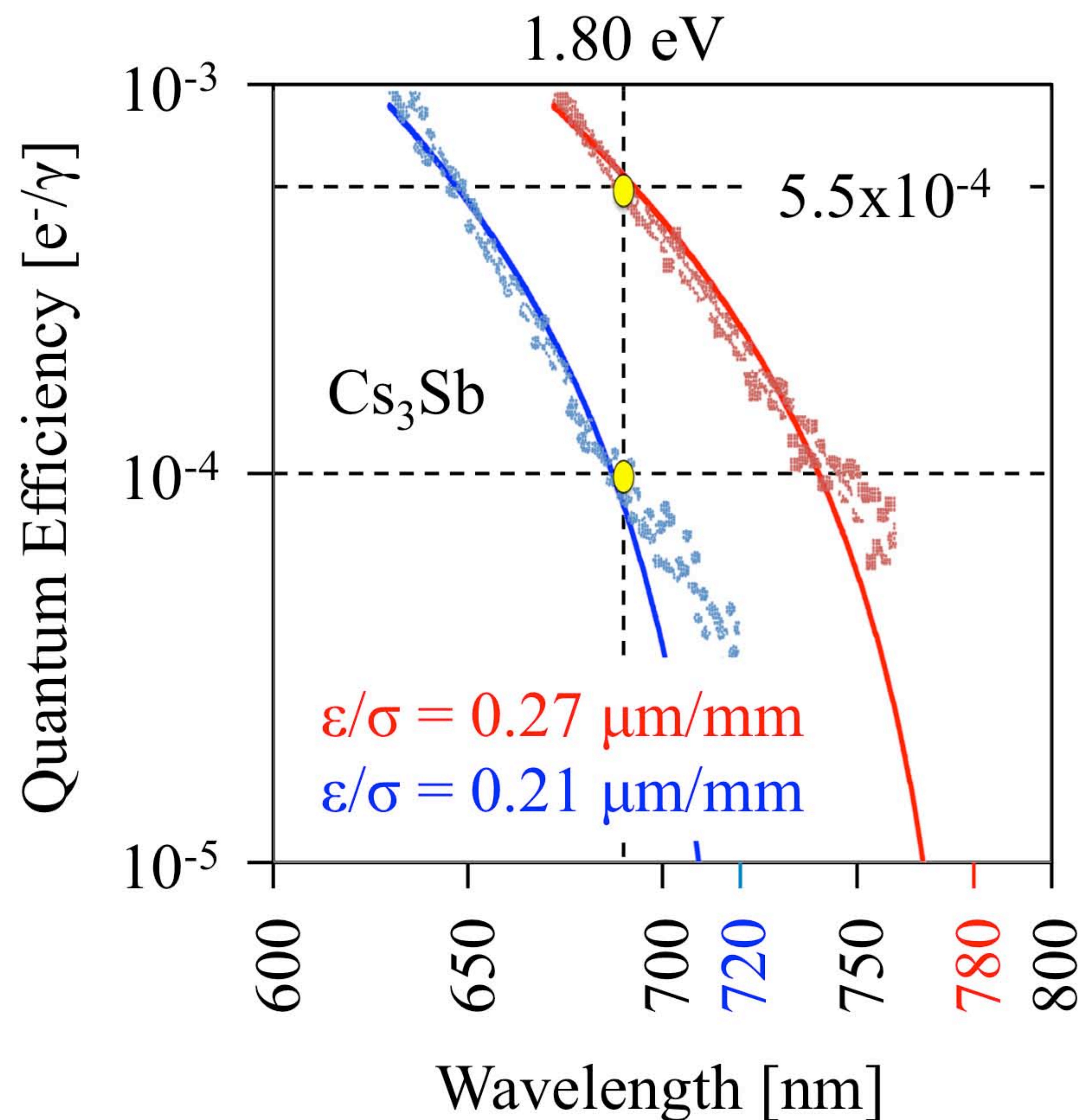
Quantum Efficiency

$$QE \propto Li_2 \left[-\text{Exp} \left[\frac{\hbar\omega - \phi + \Delta\phi}{kT} \right] \right]$$

D. Dowell and J. Schmerge, PRSTAB 12(11), 074201 (2009).

T. Vecchione et al., Proc. of the 2013 Int. FEL Conf., Manhattan, USA, TUPSO83.

Optimizing Wavelength and Temperature for Modest Reductions in Intrinsic Emittance



	Temp K	QE	Emittance $\mu\text{m/mm}$	Excess eV
Cs_3Sb	300	5.5×10^{-4}	0.27	0.21
(measured)	90	1×10^{-4}	0.21	0.08
Metals	300	2×10^{-5}	0.39	0.21
(predicted)	90	3×10^{-6}	0.23	0.08

Similar emittance but 30x QE

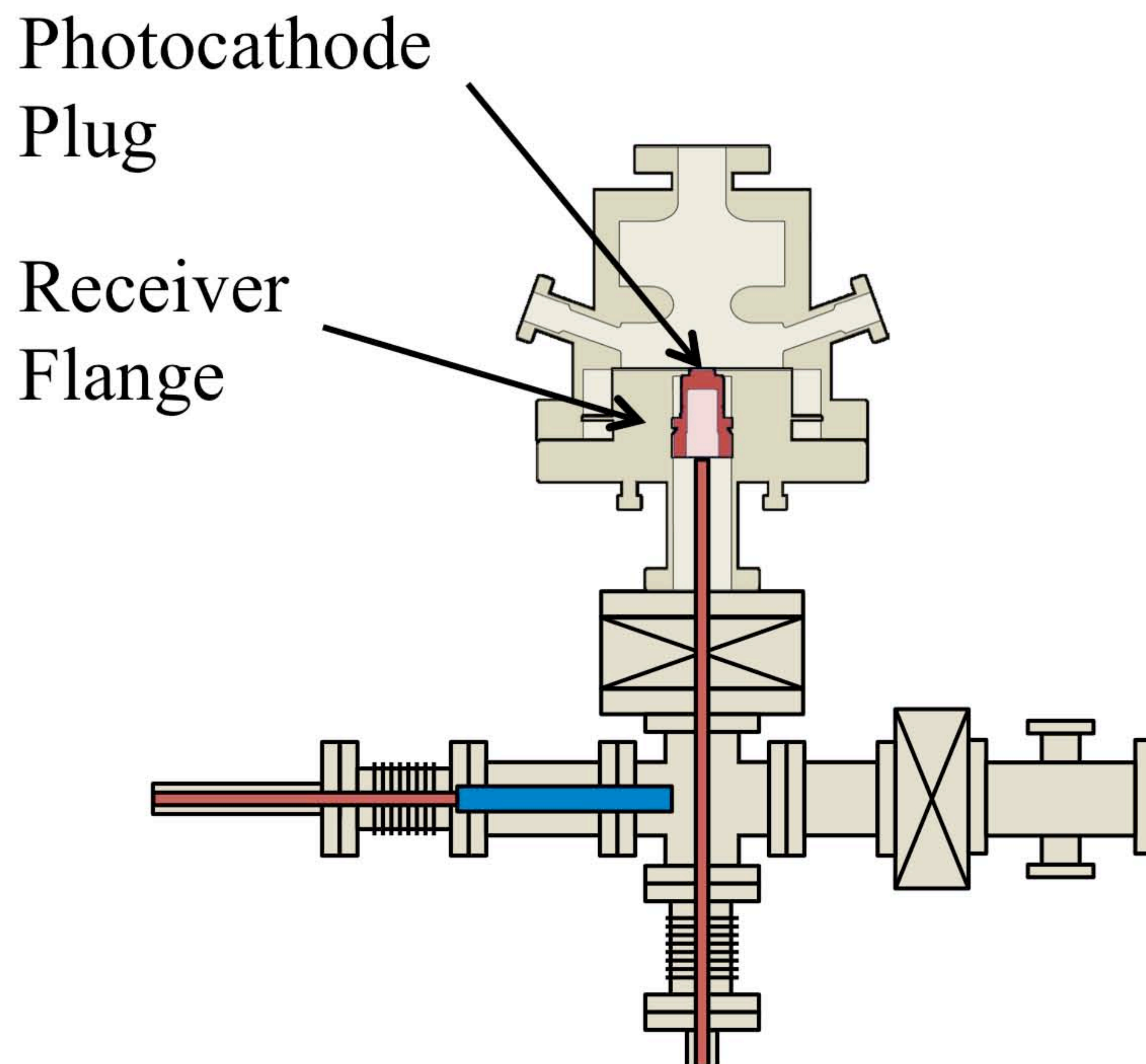
Semiconductors may dramatically outperform metals operating at cryogenic temperatures close to the photoemission threshold

L. Cultrera et al., PRSTAB 18(11), 113401 (2015)

Conceptual Designs of Photocathode Diagnostics

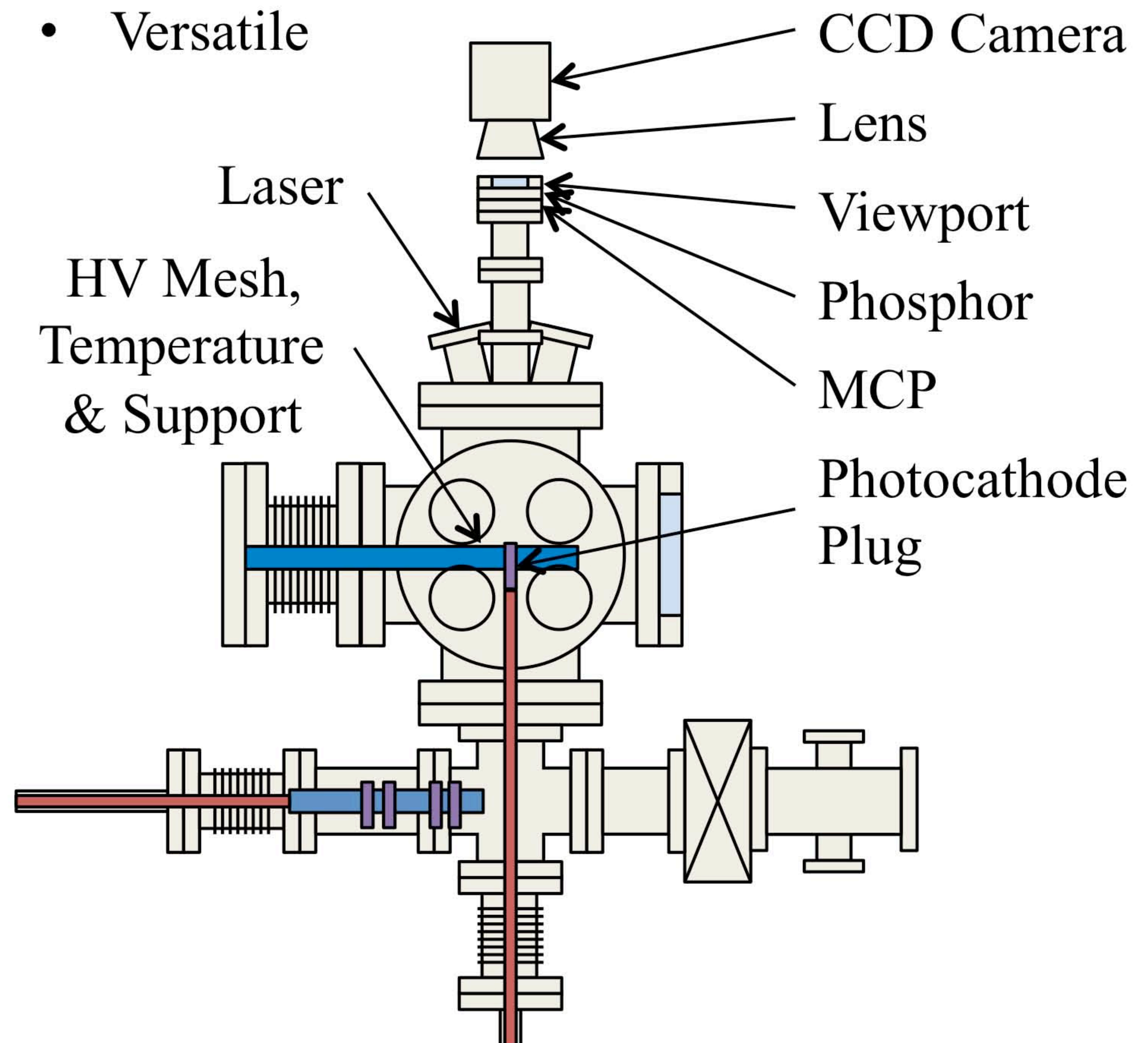
High Gradient Diagnostic

- S-Band NC RF test facility
- Results from 30 – 120 MV/m
- Decouples Photocathode R&D from Injector R&D



Low Gradient Diagnostic

- Cost effective small scale apparatus
- Results from 0 – 30 MV/m
- Versatile



Both can be used to study the effects of wavelength, temperature and surface roughness

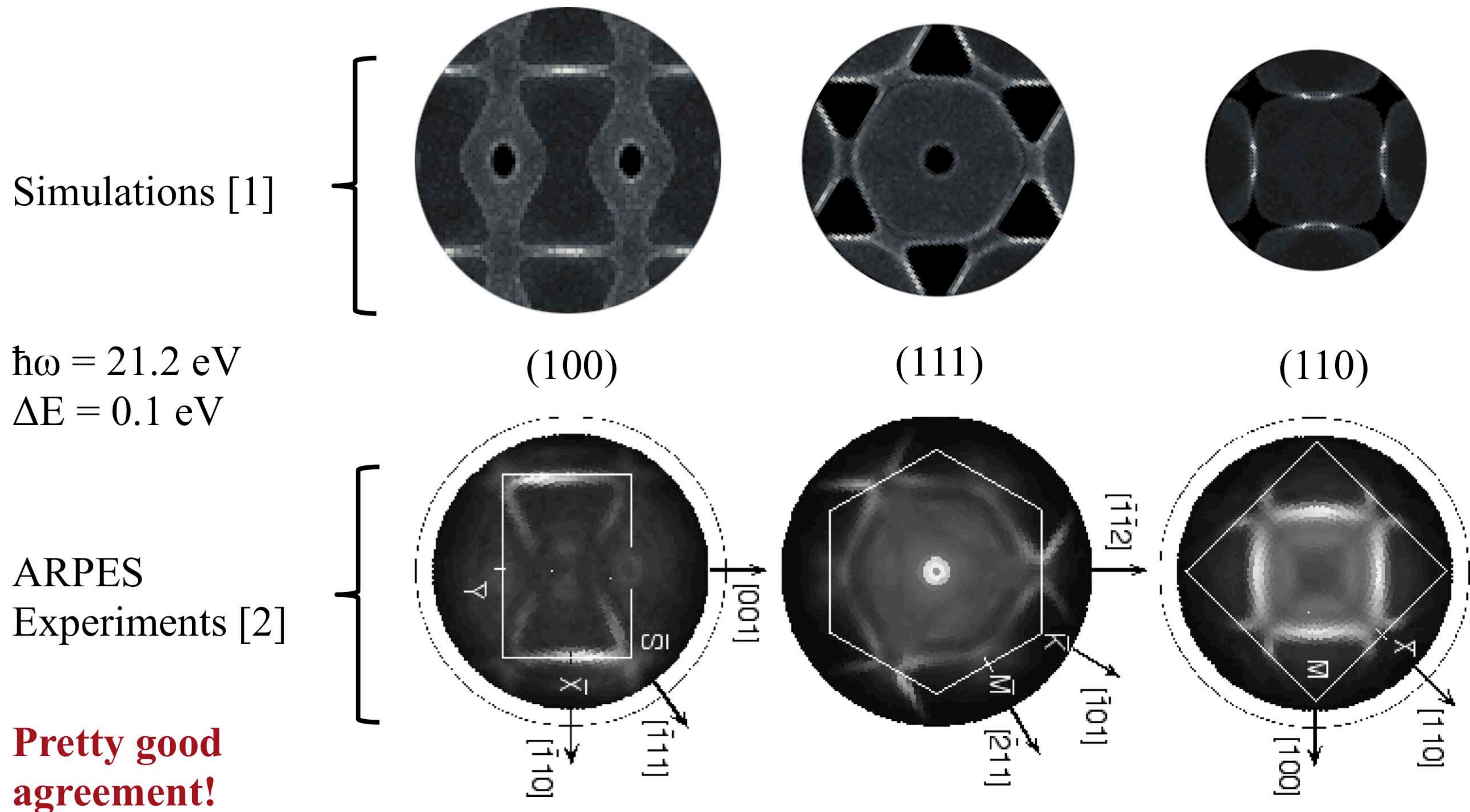
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Integrating Density-Functional Theory (DFT) into Photoemission Models to Improve Performance Predictions

- Goal: Identify photocathodes with low intrinsic emittance and high QE
- Approach: Use DFT to calculate photocathode electronic structure
Valid for metals and semiconductors
Can include the effects of finite temperatures, work function shifts in the presence of surface dipole layers and contributions from surface states
- Method: DFT results → Supply function → Photoemission model
1) K-space is populated by interpolating between DFT eigenstates
2) K-space is searched until enough occupied states w/ sufficient energy and momentum for emission are found
3) States undergo excitation and emission following photoemission model
- ABINIT: Plane wave basis and periodic boundary conditions
Troullier-Martins norm-conserving pseudopotentials replace ion cores
Exchange-correlation given by LDA Teter-Pade parameterization
Slab supercells w/ relaxed atomic positions give surface electronic structure

Photoemission Simulations Need Verification Whenever Possible to Prevent Inaccuracy



1.) T. Vecchione et al., Proc. of 2015 Int. FEL Conf., Daejeon, Korea, WEP002.

2.) Reproduced from P. Aebi et al., Surf. Sci. 307, 917-921 (1994).

Work Function & Intrinsic Emittance from Copper

ϕ [eV]	Lit. [1]	Sim. [2]
(100)	4.73 ± 0.10	4.78
(110)	4.56 ± 0.10	4.64
(111)	4.90 ± 0.02	5.01

[1] G. N. Derry et al., JVSTA 33(6), 060801 (2015).

[2] T. Vecchione et al., FEL'15, Korea, WEP002.

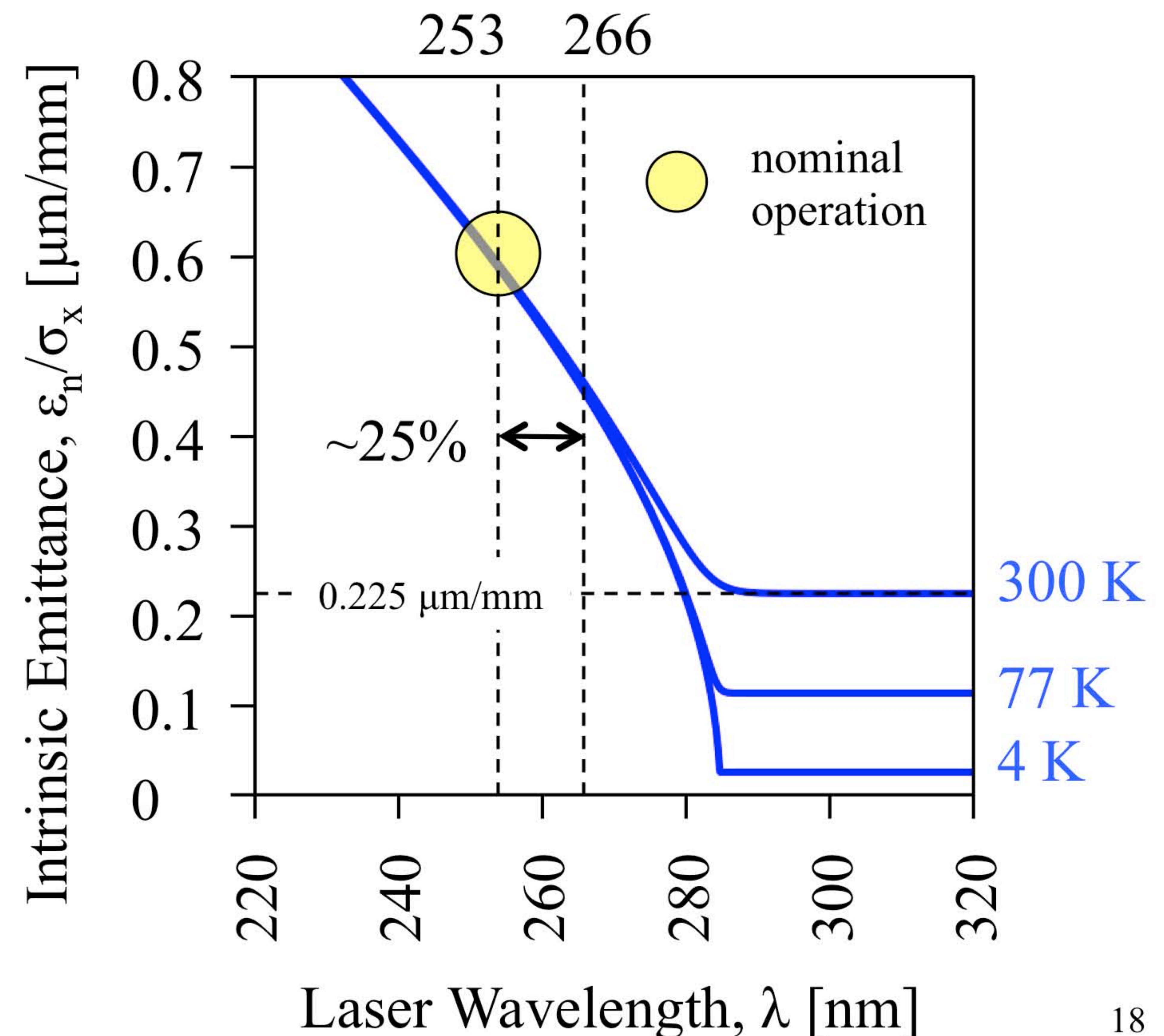
$\phi = 4.64$ eV, 120 MV/m, 30° phase

Results are consistent with literature

Cu (110) has lowest work function. It should dominate emission from polycrystalline Cu photocathodes.

Reasonable agreement with values measured at the LCLS I

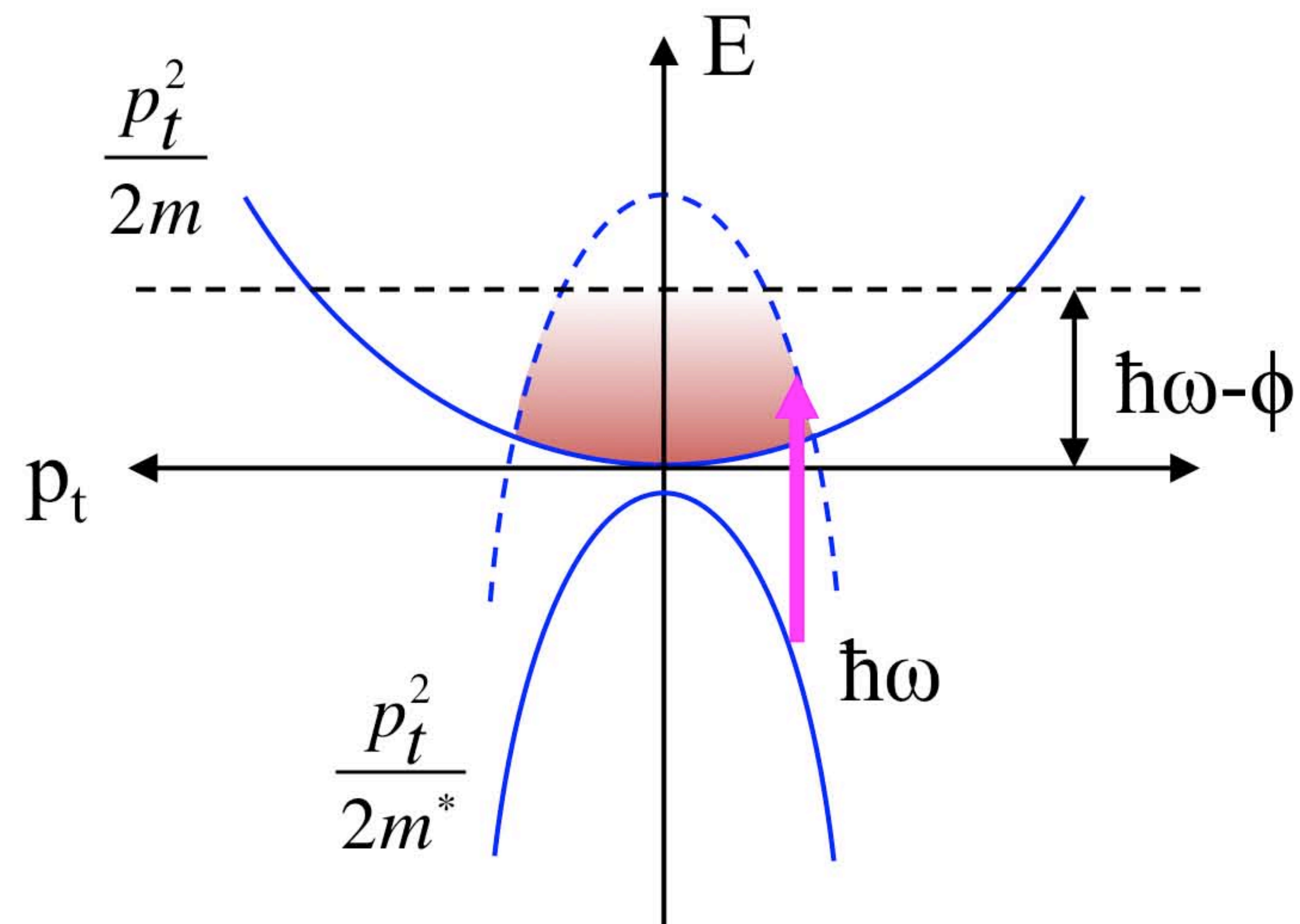
Changing laser from 253 to 266 nm reduces intrinsic emittance by 25% but requires enough laser power to compensate for a 70% drop in QE.



Low Intrinsic Emittance is Expected When $-m < m^* < 0$

$$-m < m^* < 0$$

- Lower p_t at high excess energy
- Emittance may decrease w/ temperature



Initially looking for single crystal surfaces with isolated emitting states that have small effective mass

Li		Be		(100) surfaces of BCC metals						
Na		Mg		(111) surfaces of FCC metals						
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag
Cs	Ba		Hf	Ta	W	Re	Os	Ir	Pt	Au

Plans also include semiconductors with small effective masses at their band gaps

Conclusions

Supplying Photocathodes for the LCLS II

- Purchasing photocathodes from 2017 until the middle of 2018
- Be ready to produce photocathodes by the start of 2019

Modest Photocathode Optimization for Future FELs

- Use high QE semiconductors operating near the emission threshold
- Optimize laser wavelength and temperature, minimize surface roughness
- Goal is to reduce intrinsic emittance by a factor of two

Simulations for Predicting Significant Photocathode Improvements

- Need to develop reliable, cost-effective, time-efficient simulation codes
- Longer term, more ambitious effort but the benefits could be significant
- Goal is to reduce intrinsic emittance to below the thermal limit

Thank you all very much for your attention!

Work supported by US DOE contract DE-AC02-76SF00515